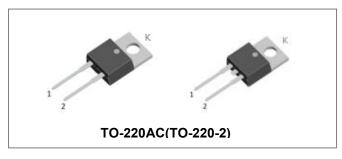






S3D15065A 650V SIC POWER SCHOTTKY RECTIFIER



Description

S3D15065A is a SiC Schottky rectifier packaged in TO-220AC(TO-220-2) case. The device is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S3D15065A is ideal for energy sensitive, high frequency applications in challenging environments.

Circuit Diagram



Applications

- · Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

Features

- 175°C T_J operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Maximum Ratings

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{DC}	-	650	V
	I _{F (AV)1}	Tc=25°C	42	А
Average Rectified Forward Current	I _{F (AV)2}	Tc=135°C	18	А
	I _{F (AV)3}	Tc=145°C	15	А
Repetitive Peak Forward Surge Current	I _{FRM1}	10ms, Half Sine pulse, T _C =25°C	50	Α
	I _{FRM2}	10ms, Half Sine pulse, T _C =110°C	35	Α
	I _{FSM1}	10ms, Half Sine pulse, T _C =25°C	102	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM2}	10ms, Half Sine pulse, T _C =110°C	65	Α
Non Bonotitive Book Forward Surge Current	I _{F,Max1}	10μs. Pulse, T _C =25°C	865	Α
Non-Repetitive Peak Forward Surge Current	I _{F,Max2}	10µs. Pulse, T _C =110°C	590	Α
B	P _{tot1}	T _C =25°C	116	W
Power Dissipation	P _{tot2}	T _C =110°C	50	W
		M3 Screw	1	Nm
TO-220 Mounting Torque	_	6-32 Screw	8.8	bf-in

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 15A, Pulse, T _J = 25 °C	1.4	1.7	V
	V _{F2}	@ 15A, Pulse, T _J = 175 °C	1.6	2.0	V
Reverse Current*			0.3	15	uA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 175 ^{\circ}\text{C}$	3	150	uA
Junction Capacitance	Ст	V _R =0V, T _J =25°C, f=1MHz	1243	-	pF
Reverse Recovery Charge	Qc	I_F = 15A, di/dt = 200A/ μ s VR = 400 V, T _J =25°C	77.5	-	nC
Capacitance Stored Energy	Ec	V _R = 400 V, T _J =25°C	18.99	-	μJ

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

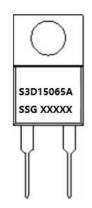
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	Rejc	DC operation	1.3	°C/W

Ordering Information

Device	Package	Shipping
S3D15065A	TO-220AC(TO-220-2)	50pcs / tube

Marking Diagram



Where XXXXX is YYWWL

 S3D
 = Device Type

 A
 = Package type

 15
 = Forward Current (15A)

 065
 = Reverse Voltage (650V)

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

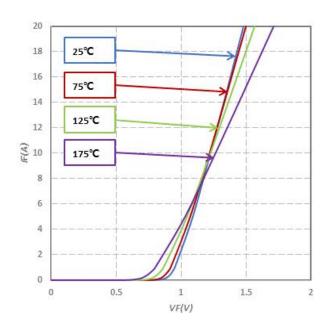
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Ratings and Characteristics Curves



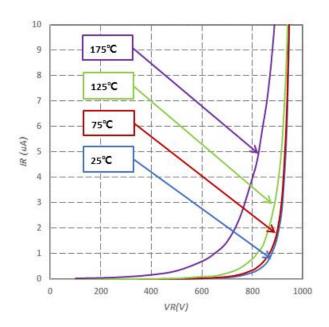


Fig.1-Typical Forward Voltage Characteristics

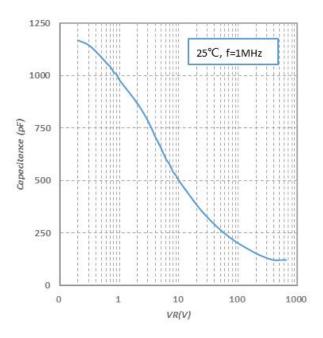


Fig.2-Typical Reverse Characteristics

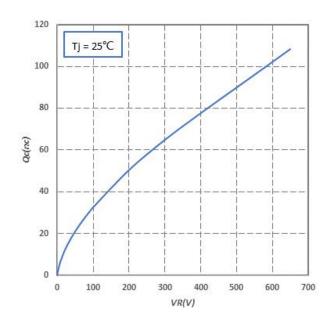


Fig.3-Capacitance vs. Reverse Voltage

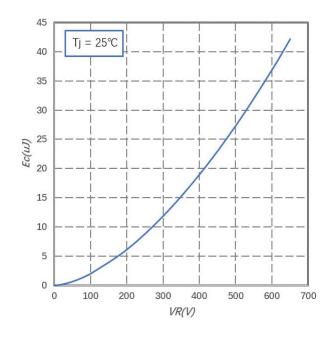
Fig.4-Total Capacitance Charge vs. Reverse Voltage

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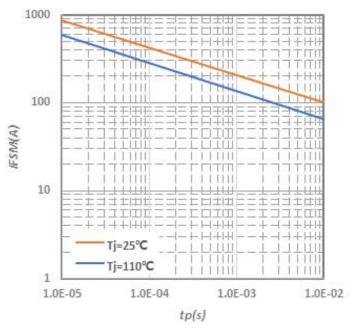


Fig.5-Capacitance Stored Energy

Fig.6-Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

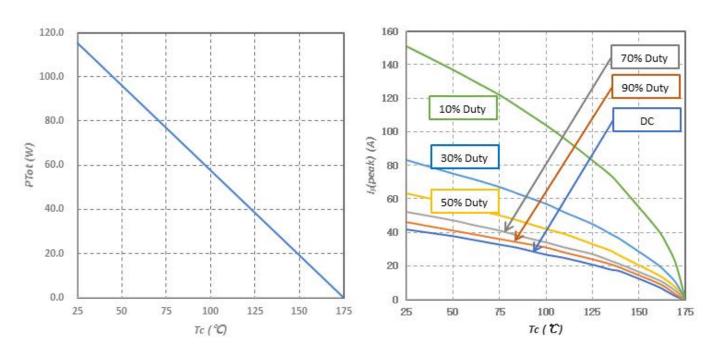


Fig.7-Power Derating

Fig.8-Current Derating

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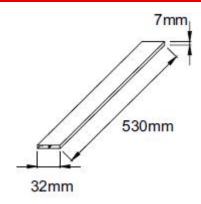
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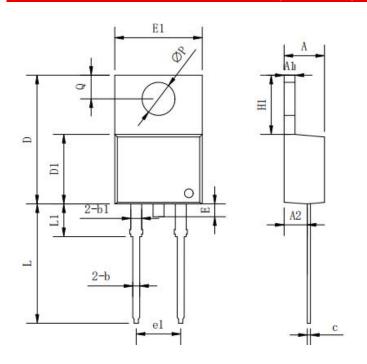




Tube Specification(TO-220-2)



Mechanical Dimensions TO-220AC(TO-220-2)



Symbol	Dimensions in millimeters			
•	Min.	Typical	Max.	
Α	3.56	-	4.83	
A1	0.51	-	1.40	
A2	2.03	-	2.92	
b	0.38	-	1.02	
b1	1.14	•	1.78	
С	0.31	-	0.61	
D	14.22	-	16.51	
D1	8.38	-	9.42	
E	1	-	1.78	
E1	9.65	10.16	10.67	
e1	-	5.08	-	
H1	5.84	-	6.86	
L	12.70	-	14.73	
L1	-	-	6.35	
ФР	-	3.56	-	







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